NSN 5962-01-081-3447

Memory Microcircuit - Page 1 of 1



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Body Length:

Between 0.740 inches and 0.780 inches

Body Width:

Between 0.250 inches and 0.300 inches

Body Height:

Between 0.140 inches and 0.170 inches

Maximum Power Dissipation Rating:

342.0 milliwatts

Operating Tempurature Range:

-10.0/+80.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

3-state output and dc coupled and high speed and hermetically sealed and monolithic and negative outputs and positive outputs

Inclosure Material:

Ceramic and glass

Inclosure Configuration:

Dual-in-line

Output Logic Form:

N-type metal oxide-semiconductor logic

Input Circuit Pattern:

13 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

7.0 volts power source

Time Rating Per Chacteristic:

250.00 nanoseconds propagation delay time, low to high level output and 250.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Ram

Memory Capacity:

Unknown

Terminal Type And Quantity:

16 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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